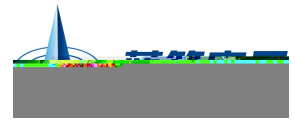


修订记录

A	2022.4.7		JSCJ-DTC123JKA+JSCJ-DTA1 23JKA+LRC-LMUN5335DW1 T1G		



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描述

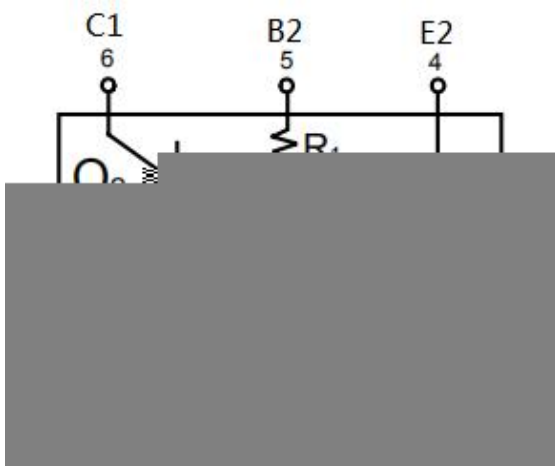
silicon NPN and PNP transistor in a SOT-363 Plastic Package

特征

With built-in bias resistors, simplify circuit design, reduce a quantity of parts and manufacturing process, HF Product.

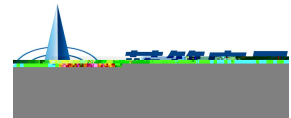
用途

Switching applications, interface circuit and driver circuit applications.



放大及印章代码

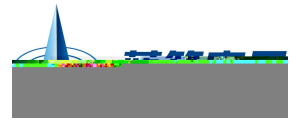
Marking	H335
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Parameter	Symbol	Rating	Unit
Supply Voltage	V_{CC}	50	V
Input Voltage	V_{IN}	12	V
		-5	V
Output Current	I_O	100	mA
Collector Dissipation	P_C	187	mW
Junction Temperature	T_J	150	
Storage Temperature Range	T_{stg}	-55~150	

Parameter

Symbol



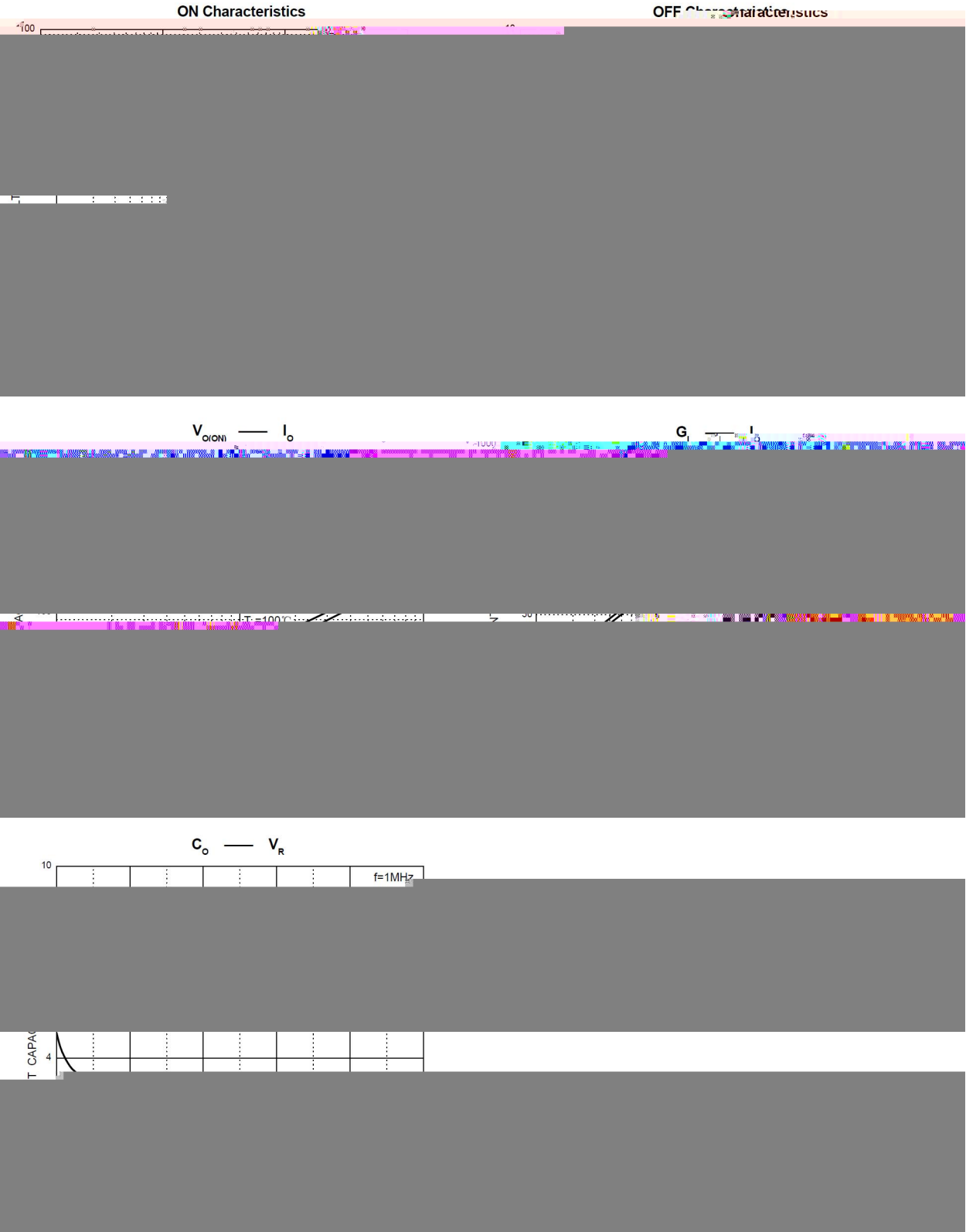
Rev.A Apr.-2022

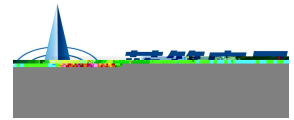
Parameter	Symbol	Rating	Unit
Supply Voltage	V_{CC}	-50	V
Input Voltage	V_{IN}	-12	V
		5	V
	I_b	-100	mA

Power Dissi



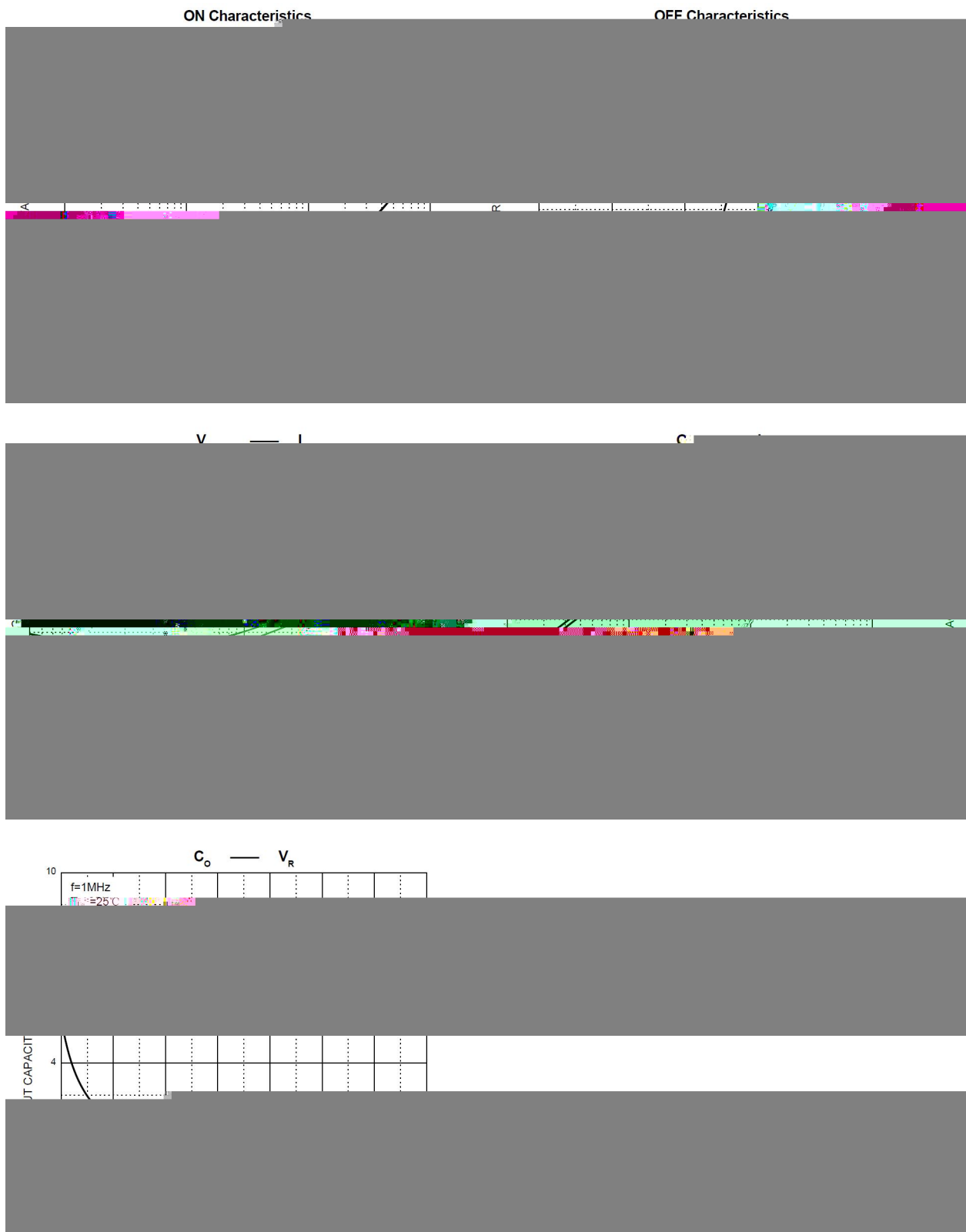
电参数曲线图





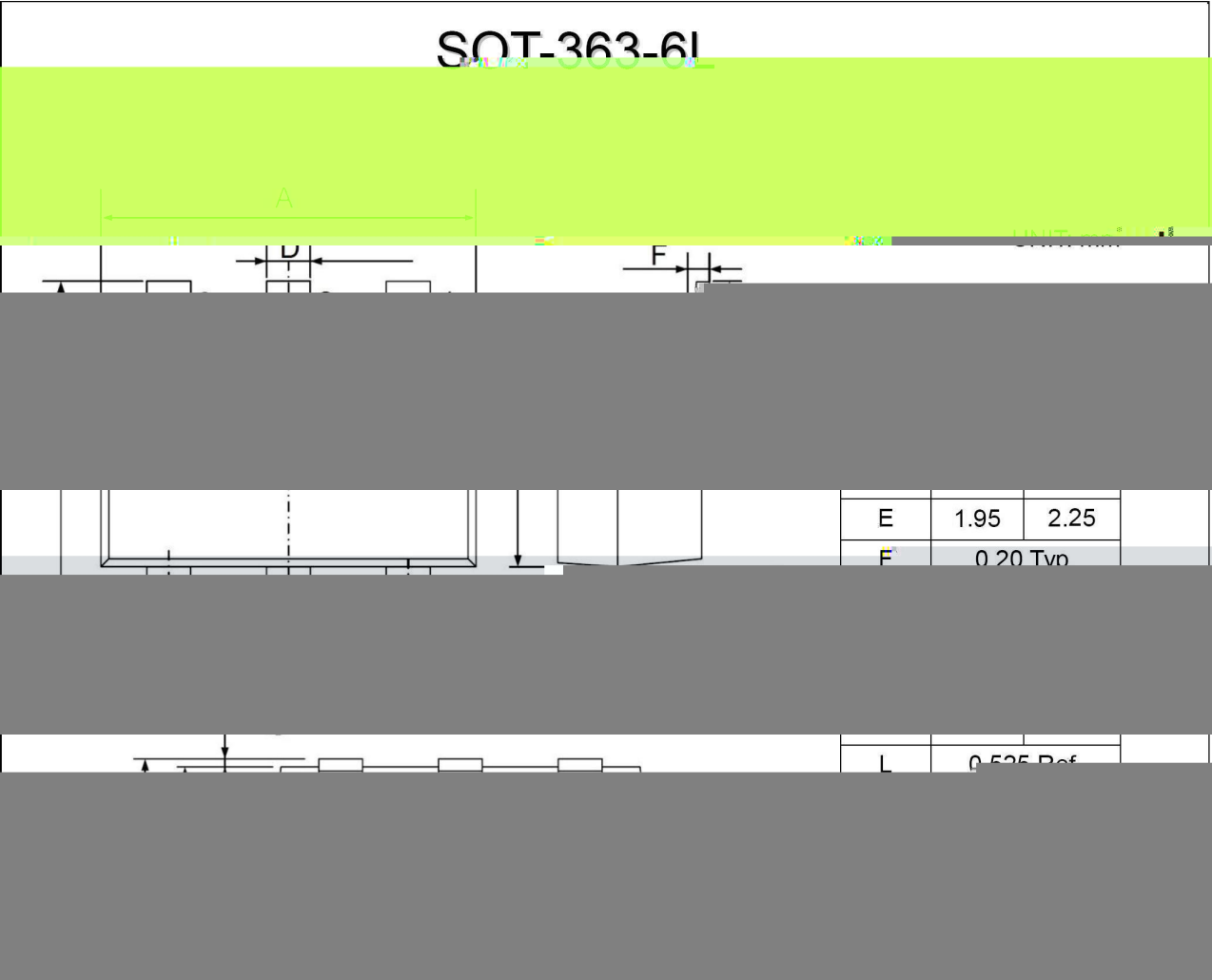
Rev.A Apr.-2022

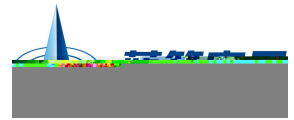
电参数曲线图





外形尺寸图







回流焊温度曲线图 无铅 Temperature Profile for IR Reflow Soldering (Pb-Free)

- Note:
- 1

150 ~ 180

60 ~ 90sec;

1.Preheating:150~180 , Time:60~90sec.
- 2

245 ~ 260

5 ~ 10sec;